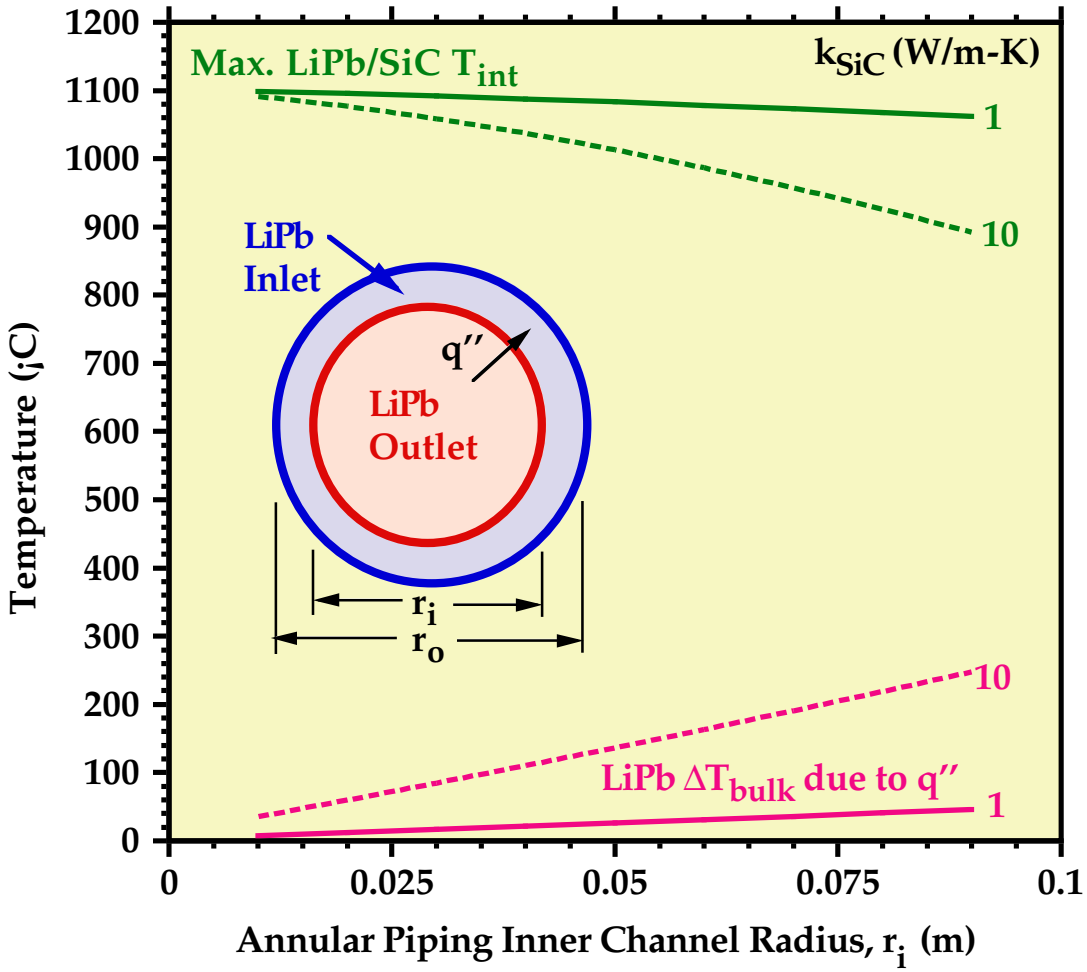
Max. LiPb/SiC T_{int}
k_{SiC} (W/m-K)
1
10
LiPb
Inlet
q''
LiPb
Outlet
r_i
r_o
10
LiPb ΔT_{bulk} due to q''
1
Temperature (¡C)
Annular Piping Inner Channel Radius, r_i (m)
0
100
200
300
400
500
600
700
800
900
1000
1100
1200
0
0.025
0.05
0.075
0.1